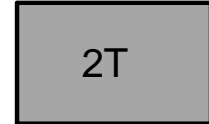
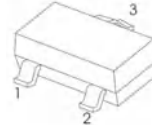




## FEATURES

- Switching Transistor

SOT-23



- 1.BASE  
2.EMITTER  
3.COLLECTOR

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

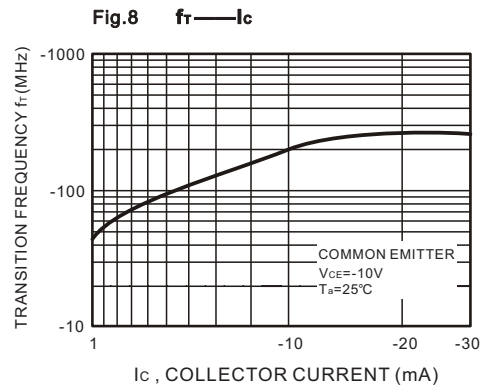
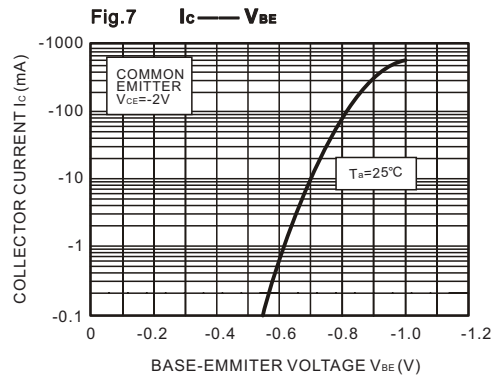
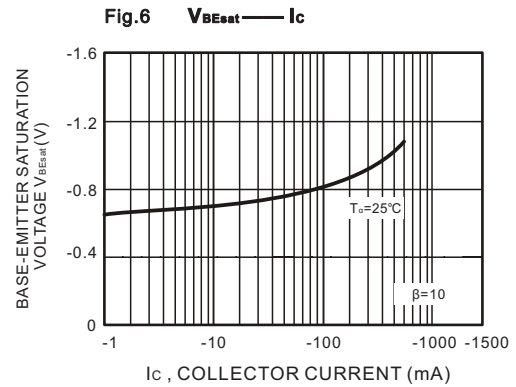
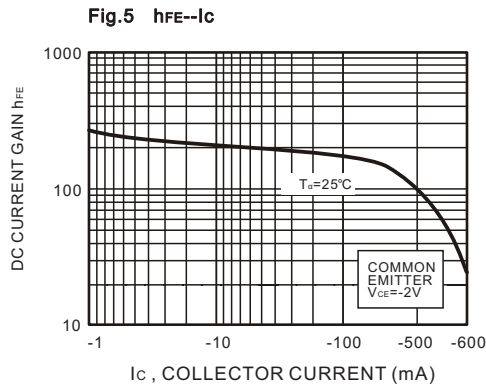
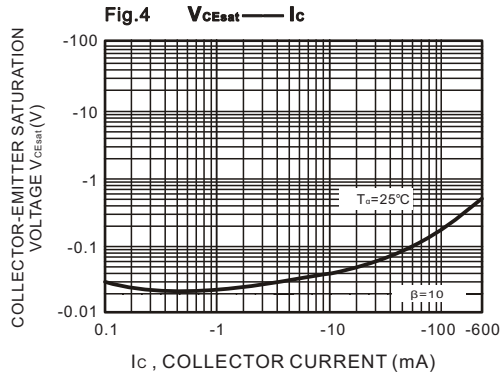
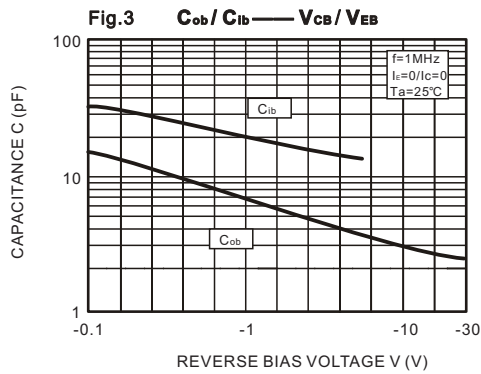
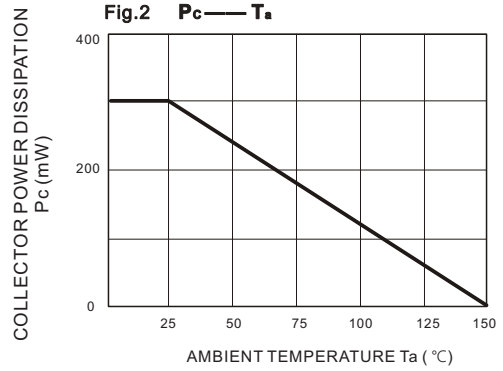
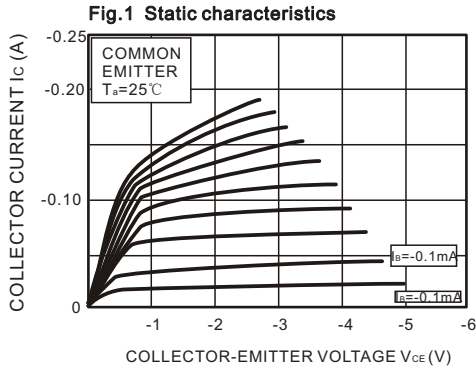
### MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector–Base Voltage	$V_{CBO}$	-40	V
Collector–Emitter Voltage	$V_{CEO}$	-40	V
Emitter–Base Voltage	$V_{EBO}$	-5	V
Collector Current — Continuous	$I_C$	-600	mA
Collector Power Dissipation	$P_C$	300	mW
Thermal Resistance From Junction To Ambient	$R_{thJA}$	417	°C/W
Operation Junction and Storage Temperature Range	$T_J, T_{stg}$	-55~+150	°C

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted.)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0$	-40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -1\text{ mA}, I_B = 0$	-40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0$	-5			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -35V, I_E = 0$			-0.1	$\mu A$
Collector cut-off current	$I_{CEX}$	$V_{CE} = -35V, V_{EB} = 0.4V$			-0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -4V, I_C = 0$			-0.1	$\mu A$
DC current gain	$h_{FE1}$	$V_{CE} = -1V, I_C = -0.1\text{ mA}$	30			
	$h_{FE2}$	$V_{CE} = -1V, I_C = -1\text{ mA}$	60			
	$h_{FE3}$	$V_{CE} = -1V, I_C = -10\text{ mA}$	100			
	$h_{FE4}$	$V_{CE} = -2V, I_C = -150\text{ mA}$	100		300	
	$h_{FE5}$	$V_{CE} = -2V, I_C = -500\text{ mA}$	20			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$			-0.4	V
		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-0.75	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$			-0.95	V
		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-1.3	V
Transition frequency	$f_T$	$V_{CE} = -10V, I_C = -20\text{ mA}, f = 100\text{ MHz}$	200			MHz
Delay time	$t_d$	$V_{CC} = -30V, V_{BE(off)} = -0.5V$			15	ns
Rise time	$t_r$	$I_C = -150\text{ mA}, I_{B1} = -15\text{ mA}$			20	ns
Storage time	$t_s$	$V_{CC} = -30V, I_C = -150\text{ mA}$			225	ns
Fall time	$t_f$	$I_{B1} = I_{B2} = -15\text{ mA}$			60	ns

RATING AND CHARACTERISTIC CURVES



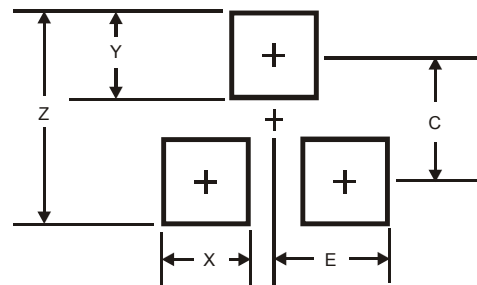
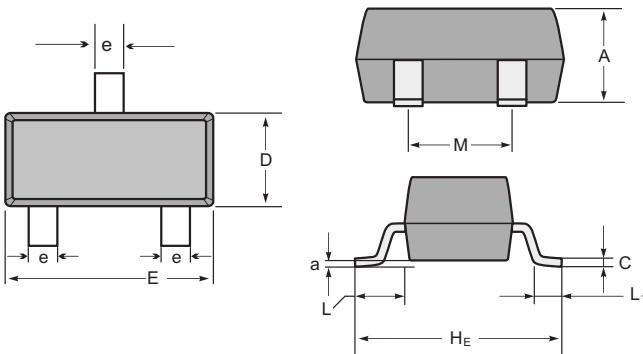
**Soldering parameters**

Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp ( $T_L$ ) to peak)		3°C/sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature( $T_L$ )(Liquid us)	+217°C
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_P$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp ( $T_P$ )		8 min. Max
Do not exceed		+260°C



**Package Dimensions & Suggested Pad Layout**

**SOT23**



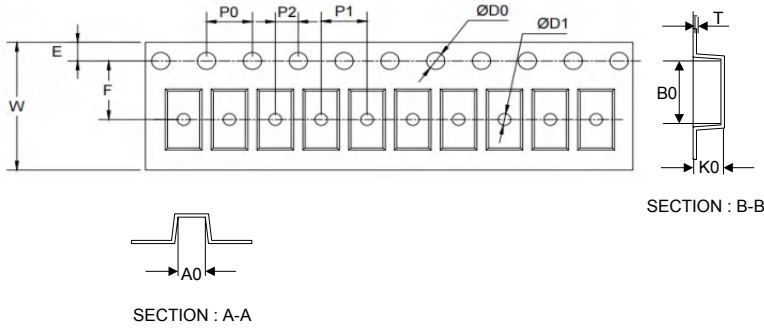
**SOT-23 mechanical data**

UNIT	A	C	D	E	He	e	M	L	L1	a	
mm	max	1.1	0.15	1.4	3.0	2.6	0.5	1.95	0.55 (ref)	0.36 (ref)	0.0
	min	0.9	0.08	1.2	2.8	2.2	0.3	1.7			0.15
mil	max	43	6	55	118	102	20	77	22 (ref)	14 (ref)	0.0
	min	35	3	47	110	87	12	67			6

Dimensions	SOT23
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

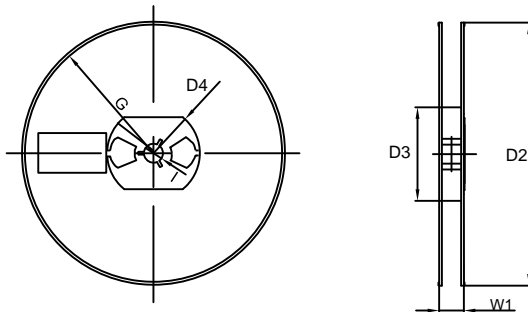
Tape & reel specification

Tape



Symbol	Dimension (mm)
P0	4.00±0.10
P1	4.00±0.10
P2	2.00±0.10
D0	1.55±0.10
D1	1.05±0.10
E	1.55±0.10
F	3.60±0.10
W	8.00±0.10
A0	3.80±0.20
B0	3.25±0.20
K0	1.45±0.10
T	0.25±0.05
D2	178.0±3.0
D3	55Min.
D4	R24.0±3.0
G	R82.0±3.0
I	13.0±2.0
W1	11.0±3.0

7" Reel



Quantity: 3000PCS